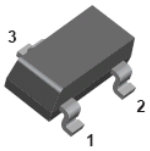
BC856/857/858
PNP general purpose Transistor

RoHS COMPLIANT

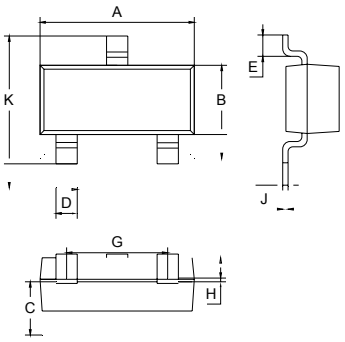


FEATURES

- Low current.(max.100mA).
- Low voltage..

APPLICATIONS

- General purpose switching and amplification.



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60
All Dimensions in mm		

ORDERING INFORMATION

Type No.	Marking	Package Code
BC856A/B	3A/3B	SOT-23
BC857A/B/C	3E/3F/3G	SOT-23
BC858A/B/C	3J/3K/3L	SOT-23

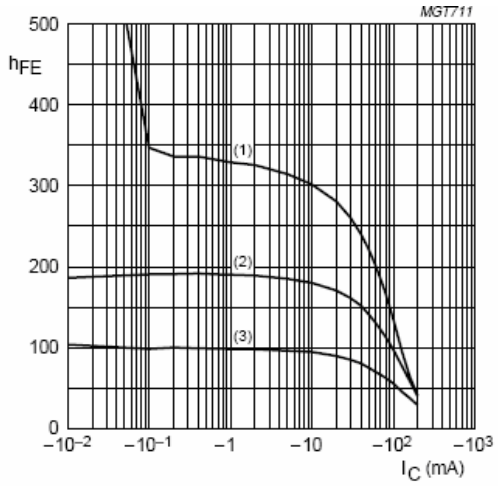
MAXIMUM RATING @ Ta=25℃ unless otherwise specified

Symbol	Parameter		Value	Units
V_{CBO}	Collector-Base Voltage	BC856 BC857 BC858	-80 -50 -30	V
V_{CEO}	Collector-Emitter Voltage	BC856 BC857 BC858	-65 -45 -30	V
V_{EBO}	Emitter-Base Voltage		-5	V
I_C	Collector Current -Continuous		-0.1	A
P_C	Collector Dissipation		250	mW
T_j,T_{stg}	Junction and Storage Temperature		-65 to +150	℃

ELECTRICAL CHARACTERISTICS @ Ta=25℃ unless otherwise specified

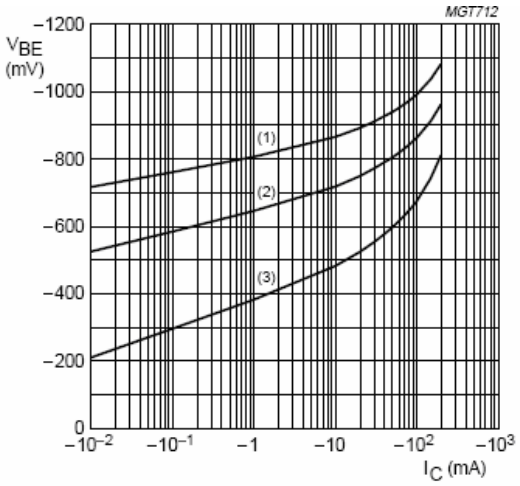
Parameter		Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	BC856 BC857 BC858	$V_{(BR)CBO}$	I_C=-10μA,I_E=0	-80 -50 -30			V
Collector-emitter breakdown voltage	BC856 BC857 BC858	$V_{(BR)CEO}$	I_C=-10mA,I_B=0	-65 -45 -30			V
Emitter-base breakdown voltage		$V_{(BR)EBO}$	I_E=-1μA,I_C=0	-5			V
Collector cut-off current		I_{CBO}	V_{CB}=-30V,I_E=0		-1	-15	nA
Emitter cut-off current		I_{EBO}	V_{EB}=-5V,I_C=0			-0.1	μA
DC current gain	BC856A,857A,858A BC856B,857B,858B BC857C,858C	h_{FE}	V_{CE}=-5V,I_C=-2mA	125 220 420		250 475 800	
Collector-emitter saturation voltage		$V_{CE(sat)}$	I_C=-100mA, I_B=-5mA I_C=-10mA, I_B=-0.5mA			-0.65 -0.3	V
Base-emitter saturation voltage		$V_{BE(sat)}$	I_C=-10mA, I_B=-0.5mA I_C=-100mA, I_B=-5mA		-0.7 -0.85		V
Base-emitter voltage		$V_{BE(on)}$	I_C=-2mA,V_{CE}=-5V I_C=-10mA,V_{CE}=-5V	-0.6	-0.65	-0.75 -0.82	V
collector capacitance		C_c	V_{CB}=-10V,I_E=I_e=0 f=1MHz		4.5		pF
Transition frequency		F	I_C=-200uA,V_{CE}=-5V, R_S=2kΩ,f=1kHz, B=200Hz		2	10	dB
Transition frequency		f_T	V_{CE}=-5V, I_C= -10mA f=100MHz	100			MHz

TYPICAL CHARACTERISTICS @ Ta=25℃ unless otherwise specified



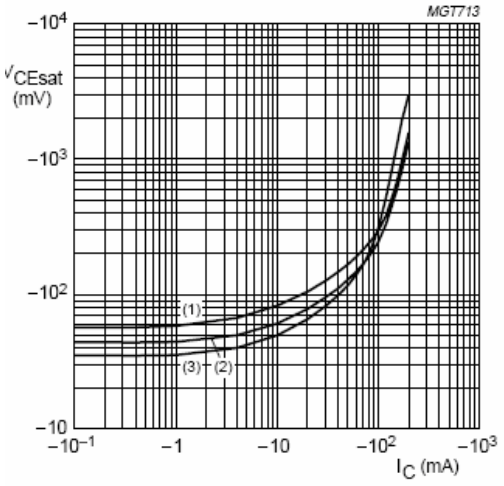
BC857A; V_{CE} = −5 V.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.1 DC current gain as a function of collector current; typical values.



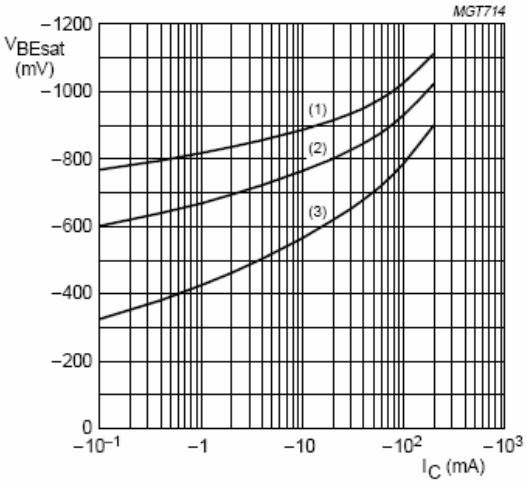
BC857A; V_{CE} = −5 V.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.2 Base-emitter voltage as a function of collector current; typical values.



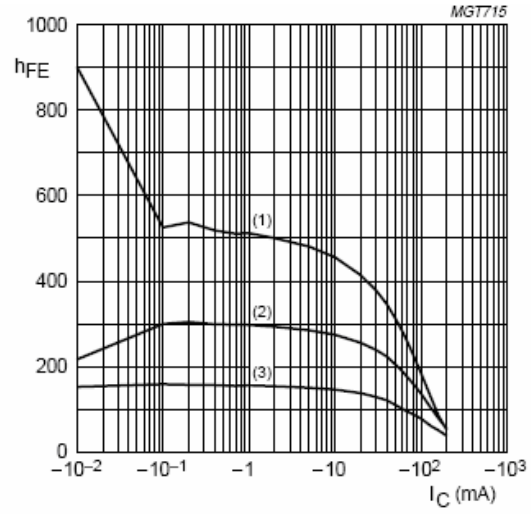
BC857A; I_C/I_B = 20.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.3 Collector-emitter saturation voltage as a function of collector current; typical values.



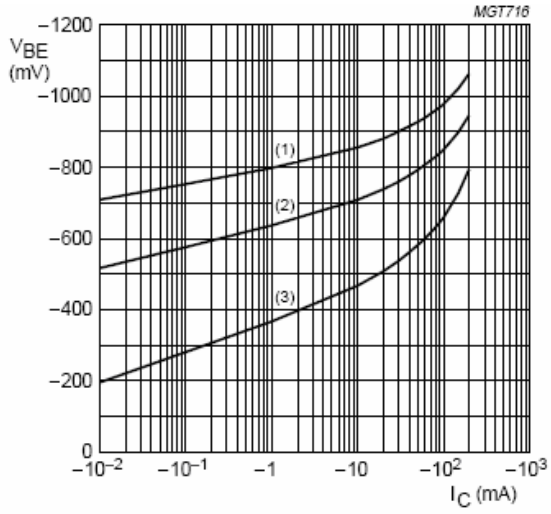
BC857A; I_C/I_B = 20.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.4 Base-emitter saturation voltage as a function of collector current; typical values.



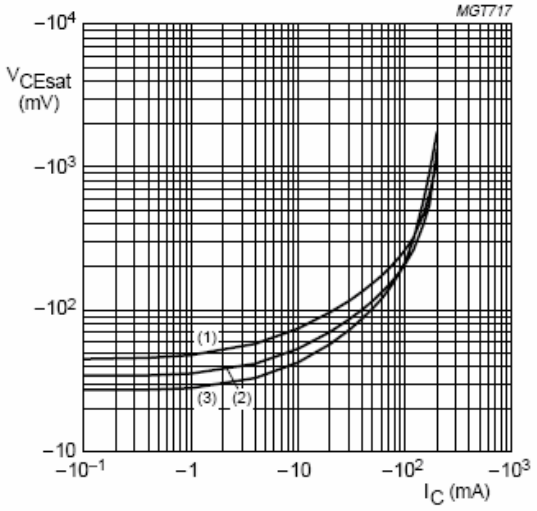
BC857B; V_{CE} = −5 V.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.5 DC current gain as a function of collector current; typical values.



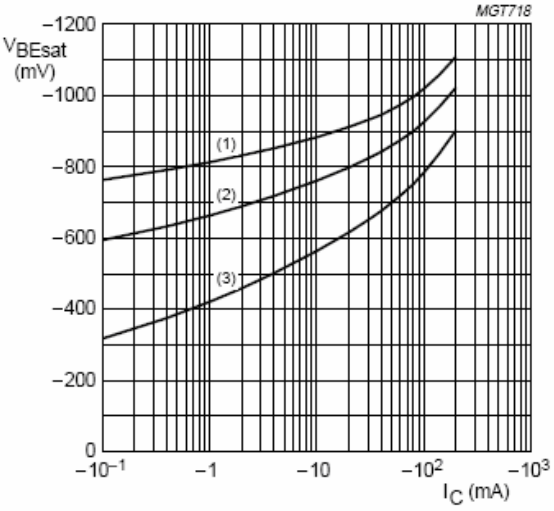
BC857B; V_{CE} = −5 V.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.6 Base-emitter voltage as a function of collector current; typical values.



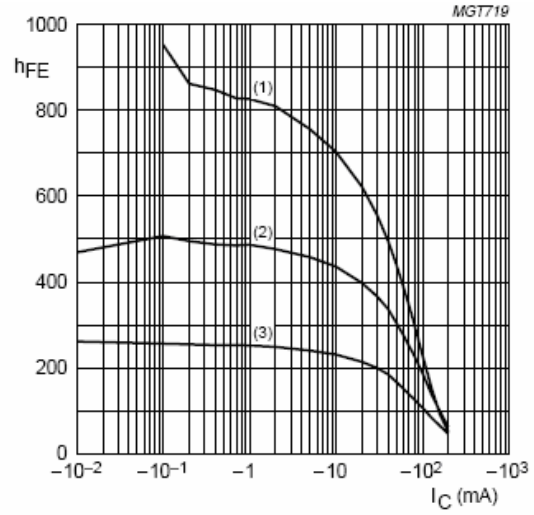
BC857B; I_C/I_B = 20.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.7 Collector-emitter saturation voltage as a



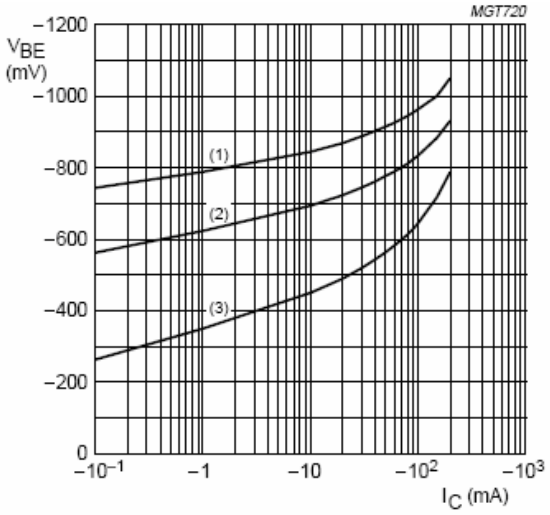
BC857B; I_C/I_B = 20.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.8 Base-emitter saturation voltage as a



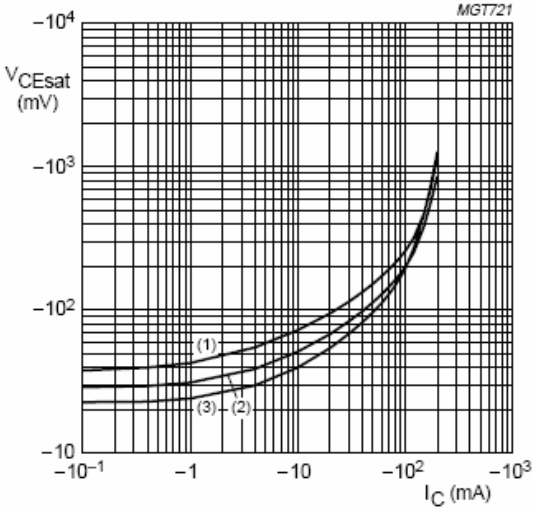
BC857C; V_{CE} = −5 V.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.9 DC current gain as a function of collector current; typical values.



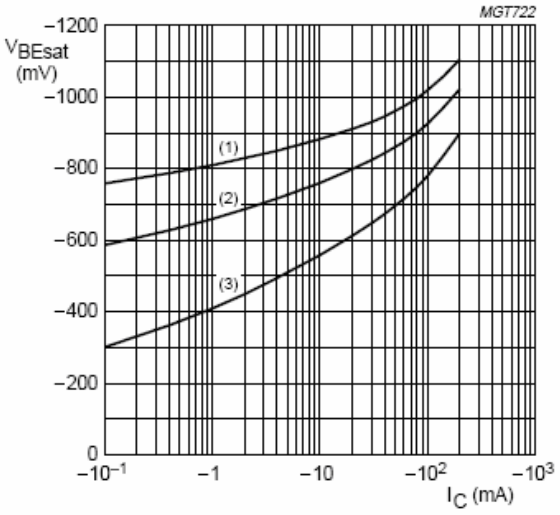
BC857C; V_{CE} = −5 V.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.10 Base-emitter voltage as a function of collector current; typical values.



BC857C; I_C/I_B = 20.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = −55 °C.

Fig.11 Collector-emitter saturation voltage as a function of collector current; typical values.



BC857C; I_C/I_B = 20.
(1) T_{amb} = −55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.12 Base-emitter saturation voltage as a function of collector current; typical values

Device	Package	Shipping
BC856/857/858	SOT-23	3000/Tape&Reel

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT ***category:***

Click to view products by LGE ***manufacturer:***

Other Similar products are found below :

619691C MCH4017-TL-H MJ15024/WS MJ15025/WS BC546/116 BC556/FSC BC557/116 BSW67A HN7G01FU-A(T5L,F,T NJVMJD148T4G NSVMMBT6520LT1G NTE187A NTE195A NTE2302 NTE2330 NTE2353 NTE316 IMX9T110 NTE63 NTE65 C4460 SBC846BLT3G 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA1727TLP 2SA2126-E 2SB1202T-TL-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMC5AT148 2N2369ADCSM 2SB1202S-TL-E 2SC2412KT146S 2SC4618TLN 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E BC557B TTC012(Q) BULD128DT4 JANTX2N3810 Jantx2N5416 US6T6TR KSF350 068071B